802.11b/g/n WICED Module (WM-N-BM-14)



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Datasheet

of

WM-N-BM-14 WICED Module

Introduction

The WM-N-BM-14 wireless WICED module which is a small size module and consists of a Broadcom BCM43362 single-chip, a ST STM32F205RG MCU, and a 2.4G antenna. The WM-N-BM-14 provides for the highest-level integration, featuring 802.11b/g and 802.11n.

It includes a 2.4 GHz WLAN CMOS power amplifier (PA) that meets the output power requirements of most handheld systems. An optional external low-noise amplifier (LNA) and external PA are also supported. Along with the integrated power amplifier, the WM-N-BM-14 also includes integrated transmit and receive baluns, further reducing the overall solution cost.

The small size & low profile physical design make it easier for system design to enable high performance wireless connectivity without space constrain. This multi- functionality and board to board physical interface provides SPI/I2C/I2S/UART interface options.

Hardware WAPI acceleration engine, AES, TKIP, WPA and WPA2 are supported to provide the latest security requirement on your network.

For the software and driver development, USI provides extensive technical document and reference software code for the system integration under the agreement of Broadcom International Ltd.

Hardware evaluation kit and development utilities will be released base on listed OS and processors to OEM customers.

Features

BCM43362 Wi-Fi

- Single band 2.4GHz IEEE 802.11b/g/n
- Supports wireless data rates up to 65Mbit/s
- Integrated RF power amplifier



STM32F205RGY6 Microprocessor

- ARM 32-bit Cortex-M3 CPU
- CPU frequency up to 120MHz
- 1 MB Flash memory
- 128 kB SRAM
- Low-power sleep, standby and stop modes
- Extend one 8Mbit Flash memory

WM-N-BM-14 Wireless Module

- Featuring integrated IEEE 802.11 b/g/n
- Supports per packet Rx Antenna diversity
- Low power consumption & excellent power management performance extend battery life.
- Small size suitable for low volume system integration.
- Easy for integration into mobile and handheld device with flexible system configuration.
- 2.412-2.484 GHz two SKUs for worldwide market.
- Lead Free design which supporting Green design requirement, RoHS Compliance.



Device Package

28x20 mm

	Change Sheet						
Rev.					Approval & Date		
		Page	Par	Change(s)			
1.1	01/15/13	All	All	Initial Release	Scarrie/Kevin		
		2		Update module picture in Introduction			
2.1	07/10/13	12	5.5	Add power table of band eange-regulatory for US/Canada and EU market	Scarrie/Kevin		
		24	10	Update recommend footprint dimension			
2.2	07/18/13	19	9.1	Update the picture of module dimension	Scarrie		
2.3	07/24/13	25 ~ 27	12	UPDATE PACKAGE AND STORAGE CONDITION	Scarrie		

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1 EXECUTIVE SUMMARY

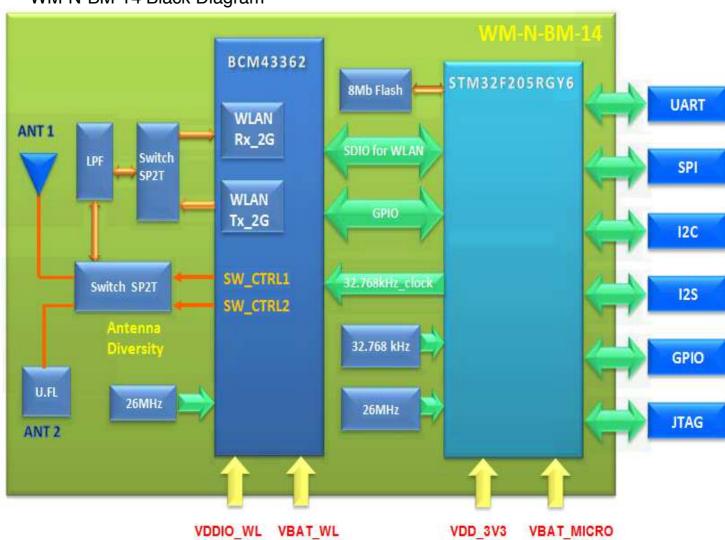
The WM-N-BM-14 module - is one of the product families in UG's product offering, targeting for system integration requiring a smaller form factor. It also provides the standard migration to high data rate to UG's current SIP customers.

The purpose of this document is to define the product specification for 802.11b/g/n WiFi module WM-N-BM-14. All the data in this document is based on Broadcom 43362 datasheet, STM32F205 datasheet and other documents provided from Broadcom and ST . The data will be updated after implementing the measurement of the module.

2 BLOCK DIAGRAM

The WM-N-BM-14 module is designed based on Broadcom 43362 chipset and ST MCU solution. It supports generic SPI, UART, I2S, I2C interface to connect the WLAN to the host processor. A simplified block diagram of the WM-N-BM-14 module is depicted in the Fig. below.

WM-N-BM-14 Black Diagram



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3 DELIVERABLES

The following products and software will be part of the product.

- WM-N-BM-14 Module with packaging
- Evaluation kits (with SPI / UART/ JTAG interface)
- Software utility which supporting customer for integration, performance test and homologation. Capable of testing, loading (firmware) and configuring (MAC, CIS) for the WM-N-BM-14 module.
- Unit Test / Qualification report
- Product Specifications.
- Agency certification pre-test report base on adapter boards

4 REFERENCE DOCUMENTS

C.I.S.P.R. Pub. 22	"Limits and methods of measurement of radio interference characteristics of information technology equipment." International Special Committee on Radio Interference (C.I.S.P.R.), Third Edition, 1997.
CB Bulletin No. 96A	"Adherence to IEC Standards: "Requirements for IEC 950, 2 nd Edition and Amendments 1 (1991), 2(1993), 3 (1995) and 4(1996). Product Categories: Meas, Med, Off, Tron." IEC System for Conformity Testing to Standards for Safety of Electrical Equipment (IECEE), April 2000.
CFR 47, Part 15-B	"Unintentional Radiators". Title 47 of the Code of Federal Regulations, Part 15, FCC Rules, Radio Frequency Devices, Subpart B.
CFR 47, Part 15-C	"Intentional Radiators". Title 47 of the Code of Federal Regulations, Part 15, FCC Rules, Subpart C. URL: http://www.access.gpo.gov/nara/cfr/waisidx_98/47cfr15_98.html
CSA C22.2 No. 950-95	"Safety of Information Technology Equipment including Electrical Business Equipment, Third Edition." Canadian Standards Association, 1995, including revised pages through July 1997.
EN 60 950	"Safety of Information Technology Equipment Including Electrical Business Equipment." European Committee for Electrotechnical Standardization (CENELEC), 1996, (IEC 950, Second Edition, including Amendment 1, 2, 3 and 4).
IEC 950	"Safety of Information Technology Equipment Including Electrical Business Equipment." European Committee for Electrotechnical Standardization, Intentional Electrotechnical Commission. 1991, Second Edition, including Amendments 1, 2, 3, and 4.
IEEE 802.11	"Wireless LAN Medium Access Control (MAC) And Physical Layer (PHY) Specifications." Institute of Electrical and Electronics Engineers. 1999.

5 TECHNICAL SPECIFICATION

5.1 ABSOLUTE MAXIMUM RATING

Supply Power	Max +3.6 Volt	
Non Operating Temperature	- 40° to 85° Celsius	
Voltage ripple	+/- 2%	Max. Values not exceeding Operating
		voltage

5.2 RECOMMENDABLE OPERATION CONDITION

5.2.1 TEMPERATURE, HUMIDITY

The WM-N-BM-14 module has to withstand the operational requirements as listed in the table below.

Operating Temperature	-20° to 75° Celsius	
Humidity range	Max 95%	Non condensing, relative humidity

^{*} The maximum operating ambient temperature range can up to 85degC, but exposure to absolute-maximum-rated conditions may cause performance degradation and affect device reliability.

5.2.2 VOLTAGE

Power supply for the WM-N-BM-14 module will be provided by the host via the power pins

<u> </u>			<u> </u>		
Symbol	Parameter	Min	Тур.	Max	Unit
VBAT_WL	power supply for BCM43362	3.0	3.3	3.6	V
VDDIO_3V3_WL	host Interface power supply	3.0	3.3	3.6	V
VBAT_MICRO	backup operating voltage	3.0	3.3	3.6	V
VDD_3V3	power supply for MCU	3.0	3.3	3.6	V

5.2.3 CURRENT CONSUMPTION

The WM-N-BM-14 on TX mode output current consumption :

(Typical spec is defined @3.3V 25°C; MAX. spec is defined @3.0V 70°C)

Current Consumption	TYP.	MAX.
Tx output power @16.5 dBm on 11b 1M	385 mA	430 mA
Tx output power @ 16.5 dBm on 11b 11M	370 mA	410 mA
Tx output power @ 15 dBm on 11g 6M	345 mA	380 mA
Tx output power @ 13 dBm on 11g 54M	290 mA	320 mA
Tx output power @ 14.5 dBm on 11n MCS0	315 mA	350 mA
Tx output power @ 12 dBm on 11n MCS7	265 mA	295 mA

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The WM-N-BM-14 on RX mode current consumption :

(Typical spec is defined @3.3V 25°C; MAX. spec is defined @3.0V 70°C)

Current Consumption	TYP.	MAX.
Rx @ 11b 1M	120 mA	150 mA
Rx @ 11b 11M	120 mA	150 mA
Rx @ 11g 6M	120 mA	150 mA
Rx @ 11g 54M	120 mA	150 mA
Rx @ 11n MCS0	120 mA	150 mA
Rx @ 11n MCS7	120 mA	150 mA

5.3 WIRELESS SPECIFICATIONS

The WM-N-BM-14 module complies with the following features and standards;

Features	Description
WLAN Standards	IEEE 802 11 b/g/n
Antenna Connecter Port	One printed antenna, one U.FL connector for external antenna
Frequency Band	2.400 GHz – 2.484 GHz
Number of Sub Channels	CH1 to CH14
Modulation	DSSS, CCK, OFDM, BPSK, QPSK,16QAM, 64QAM
Supported data rates	11b 1, 2, 5.5, 11 (Mbps)
	11g 6, 9, 12, 18, 24, 36, 48, 54 (Mbps)
	11n HT20 MCS0(6.5Mbps) to HT20 MCS7(65Mbps)

5.4 SPECIFICATIONS OF WIFI'S OUTPUT POWER . EVM . SENSITIVITY

The WM-N-BM-14 module WiFi output power as list in the table below:

Characteristics		TYP.	Criteria	Unit
	1M	16.5	+/- 1.5	dBm
RF Average Output Power, 802.11b CCK Mode	11M	16.5	+/- 1.5	dBm
	6M	15	+/- 1.5	dBm
RF Average Output Power, 802.11g OFDM Mode	54M	13	+/- 1.5	dBm
	MCS0	14.5	+/- 1.5	dBm
RF Average Output Power, 802.11n OFDM Mode	MCS7	12	+/- 1.5	dBm

WiFi TX EVM follow the IEEE spec that as list in the table below:

Characteristics	IEEE Spec	Unit	
RF Average Output EVM (11b)	@1 Mbps	-10	dB
Average Output Evivi (11b)	@11 Mbps	-10	dB
DE Average Output EVM (11a)	@6 Mbps	-5	dB
RF Average Output EVM (11g)	@54 Mbps	-25	dB
RF Average Output EVM (11n)	@ MCS0	-5	dB
The Average Output Evivi (Till)	@ MCS7	-28	dB

The WM-N-BM-14 module WiFi sensitivity as list in the table below:

Receiver Characteristics	TYP.	MAX.	Unit
PER <8%, Rx Sensitivity @ 1 Mbps	-96	-89	dBm
PER <8%, Rx Sensitivity @ 11 Mbps	-88	-84	dBm
PER <10% Rx Sensitivity @ 6 Mbps	-90	-83	dBm
PER <10%, Rx Sensitivity @ 54 Mbps	-74	-70	dBm
PER <10%, Rx Sensitivity @ MCS0	-89	-83	dBm
PER <10%, Rx Sensitivity @ MCS7	-71	-67	dBm

5.5 SPECIFICATIONS OF WIFI'S BAND EANGE-REGULATORY POWERTABLE FOR US/CANADA AND EU MARKET

The power of WiFi Band eange-regulatory for **US/Canada market** as list in the table below:

Characteristics	Channel	Power (dBm)
RF Average Output Power, 802.11b CCK Mode	1~11	16.5
	1	14.5
RF Average Output Power, 802.11g OFDM Mode	2 ~ 10	15
	11	14.5
	1	14.5
RF Average Output Power, 802.11n HT20 OFDM Mode	2 ~ 10	15
	11	14.5

The power of WiFi Band eange-regulatory for **EU market** as list in the table below:

Characteristics	Channel	Power (dBm)
RF Average Output Power, 802.11b CCK Mode	1~13	16.5
RF Average Output Power, 802.11g OFDM Mode	1 ~ 13	15
RF Average Output Power, 802.11n HT20 OFDM Mode	1 ~ 13	15

6 FLASH MEMORY

6.1 MCU EMBEDDED FLASH MEMORY

The STM32F205RG devices embed a 128-bit wide Flash memory of 1 Mbytes available for storing programs and data. It also features 512 bytes of OTP memory that can be used to store critical user data such as Ethernet MAC addresses or cryptographic keys.

For information on programming, erasing and protection of the internal Flash memory, please refer to the STM32F205RG Flash programming manual. The reference and Flash programming manuals are both available from the STMicroelectronics website *www.st.com*.

6.2 MODULE INTERNAL MEMORY FLASH

The WM-N-BM-14 have one 8M SPI Flash in the module. This devices work voltage need 3.3V power supply. It is provide 512 bytes of OTP memory that can be used to store critical user data such as Ethernet MAC addresses or cryptographic keys. It have 86MHz speed.

For information on programming, erasing and protection of this 8M Flash memory, please refer to the Macronix MX25L8006E Flash programming manual. The reference and Flash programming manuals are both available from the Macronix website *www.macronix.com*.

7 I/O PORT CHARACTERISTICS

Unless otherwise specified, the parameters given as below *Table*.

For detail information of I/O injection parameters and conditions, please refer to STM32F205RG I/O manual.

Table 7.1 I/O static characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V	Standard IO input low level voltage		-0.3		0.28*(V _{DD} -2 V)+0.8 V	٧	
V _{IL}	IO FT ⁽¹⁾ input low level voltage		-0.3		0.32*(V _{DD} -2 V)+0.75 V	٧	
	Standard IO input high level voltage		0.41*(V _{DD} -2 V)+1.3 V		V _{DD} +0.3	٧	
VIH	IO FT ⁽¹⁾ input high level	V _{DD} > 2 V	0.42*/V 2.1/1.1 V		5.5	· v	
	voltage	$V_{DD} \le 2 V$	0.42*(V _{DD} -2 V)+1 V		5.2	v	
V _{hys}	Standard IO Schmitt trigger voltage hysteresis ⁽²⁾		200			mV	
.,,.	IO FT Schmitt trigger voltage hysteresis ⁽²⁾		5% V _{DD} ⁽³⁾			mV	
l _{ikg}	Input leakage current (4)	V _{SS} ≤V _{IN} ≤V _{DD} Standard I/Os			±1	μА	
		V _{IN} = 5 V, I/O FT			3		
R _{PU}	Weak pull-up equivalent resistor ⁽⁵⁾	V _{IN} = V _{SS}	30	40	50	kΩ	
R _{PD}	Weak pull-down equivalent resistor ⁽⁵⁾	V _{IN} = V _{DD}	30	40	50	kΩ	
C _{IO}	I/O pin capacitance			5		pF	

- 1. FT = Five-volt tolerant. In order to sustain a voltage higher than VDD+0.3 the internal pull-up/pull-down resistors must be disabled.
- 2. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization, not tested in production.
- 3. With a minimum of 100 mV.
- 4. Leakage could be higher than max. if negative current is injected on adjacent pins.
- 5. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This MOS/NMOS contribution to the series resistance is minimum (\sim 10% order).

8 COMMUNICATIONS INTERFACE

8.1 I2C Interface Characteristics

The I2C bus interfaces can operate in multi-master and slave modes. They can support the Standard- and Fast-modes. The I2C characteristics are described in below Table. If need detail information, please refer to STM32F205RG I/O or Interface manual.

I2C characteristics

Complete	Parameter	Standard ı	node I ² C ⁽¹⁾	Fast mode	Unit		
Symbol	ranneter	Min	Max	Min	Max	Onit	
t _{w(SCLL)}	SCL clock low time	4.7		1.3		110	
t _{w(SCLH)}	SCL clock high time	4.0		0.6		μs	
t _{su(SDA)}	SDA setup time	250		100			
t _{h(SDA)}	SDA data hold time	0(3)		O ⁽⁴⁾	900 ⁽³⁾		
t _{r(SDA)} t _{r(SCL)}	SDA and SCL rise time		1000	20 + 0.1C _b	300	ns	
t _{f(SDA)} t _{f(SCL)}	SDA and SCL fall time		300		300		
t _{h(STA)}	Start condition hold time	4.0		0.6			
t _{su(STA)}	Repeated Start condition setup time	4.7		0.6		μs	
t _{su(STO)}	Stop condition setup time	4.0		0.6		μs	
t _{w(STO:STA)}	Stop to Start condition time (bus free)	4.7		1.3		μs	
C _b	Capacitive load for each bus line		400		400	pF	

- 1. Guaranteed by design, not tested in production.
- 2. fPCLK1 must be higher than 2 MHz to achieve standard mode I2C frequencies. It must be higher than 4 MHz to achieve the fast mode I2C frequencies and it must be a multiple of 10 MHz in order to reach the I2C fast mode maximum clock speed of 400 kHz
- 3. The maximum hold time of the Start condition has only to be met if the interface does not stretch the low period of SCL signal.
- 4. The device must internally provide a hold time of at least 300ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.

8.2 SPI / I2S interface characteristics

Unless otherwise specified, the SPI /I2S parameters are given in below Table.

Refer to STM32F205RG Datasheet: I/O port characteristics for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI and WS, CK, SD for I2S).

SPI characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
f _{SCK}	SDI alaak fraguanay	Master mode	-	30	MHz
1/t _{c(SCK)}	SPI clock frequency	Slave mode	-	30	1011 12
t _{r(SCL)} t _{f(SCL)}	SPI clock rise and fall time	Capacitive load: C = 30 pF	-	8	ns
DuCy(SCK)	SPI slave input clock duty cycle	Slave mode	30	70	%
t _{su(NSS)} ⁽³⁾	NSS setup time	Slave mode	4 t _{PCLK}	-	
t _{h(NSS)} ⁽³⁾	NSS hold time	Slave mode	2 t _{PCLK}	-	
t _{w(SCLH)} (3) t _{w(SCLL)} (3)	SCK high and low time	Master mode, f _{PCLK} = 30 MHz, presc = 4	TBD	TBD	
t _{su(MI)} (3)	t _{su(MI)} (3) t _{su(SI)} Data input setup time	Master mode	5	-	
t _{su(SI)} (3)		Slave mode	5	-	
t _{h(MI)} (3) t _{h(SI)} (3)	Data input hold time	Master mode	5	-	
t _{h(SI)} (3)	Data input floid time	Slave mode	4	-	ns
t _{a(SO)} (3)(4)	Data output access time	Slave mode, f _{PCLK} = 20 MHz	0	3 t _{PCLK}	
t _{dis(SO)} (3)(5)	Data output disable time	Slave mode	2	10	
t _{v(SO)} (3)(1)	Data output valid time	Slave mode (after enable edge)	-	25	
t _{v(MO)} (3)(1)	Data output valid time	Master mode (after enable edge)	-	5	
t _{h(SO)} (3)	Data output hold time	Slave mode (after enable edge)	15	-	
t _{h(MO)} (3)	Data output floid tiffle	Master mode (after enable edge)	2	-	

- 1. Remapped SPI1 characteristics to be determined.
- 2. TBD stands for "to be defined".
- 3. Based on characterization, not tested in production.
- 4. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.
- 5. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

I2S characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
f _{CK}	I ² S clock frequency	Master	TBD	TBD	MHz
1/t _{c(CK)}	1 S clock frequency	Slave	0	TBD	IVITIZ
t _{r(CK)}	I ² S clock rise and fall time	capacitive load C _L = 50 pF	-	TBD	
t _{v(WS)} (2)	WS valid time	Master	TBD	-	
t _{h(WS)} (2)	WS hold time	Master	TBD	-	
t _{su(WS)} (2)	WS setup time	Slave	TBD	-	
t _{h(WS)} (2)	WS hold time	Slave	TBD	-	
t _{w(CKH)} (2) t _{w(CKL)} (2)	CK high and low time	Master f _{PCLK} = TBD, presc = TBD	TBD	-	
t _{su(SD_MR)} (2) t _{su(SD_SR)} (2)	Data input setup time	Master receiver Slave receiver	TBD TBD	-	
t _{h(SD_MR)} (2)(3) t _{h(SD_SR)} (2)(3)	Data input hold time	Master receiver Slave receiver	TBD TBD	-	ns
t _{h(SD_MR)} (2) t _{h(SD_SR)} (2)	Data input hold time	Master f _{PCLK} = TBD Slave f _{PCLK} = TBD	TBD TBD	-	
t _{v(SD_ST)} (2)(3)	Data output valid time	Slave transmitter (after enable edge)	-	TBD	
1(22_21)		f _{PCLK} = TBD	-	TBD	
t _{h(SD_ST)} (2)	Data output hold time	Slave transmitter (after enable edge)	TBD	-	
t _{v(SD_MT)} (2)(3)	Data output valid time	Master transmitter (after enable edge)	-	TBD	
		f _{PCLK} = TBD	TBD	TBD	
t _{h(SD_MT)} (2)	Data output hold time	Master transmitter (after enable edge)	TBD	-	

- 1. TBD stands for "to be defined".
- 2. Based on design simulation and/or characterization results, not tested in production.
- 3. Depends on fPCLK. For example, if fPCLK=8 MHz, then TPCLK = 1/fPLCLK =125 ns.

8.3 UART interface characteristics

WM-N-BM-14 Module have two universal synchronous/asynchronous receiver transmitters, USART1 and USART2. The USART1 can communicate at speeds of up to 7.5 Mbit/s. And the USAR2 interfaces communicate at up to 3.75 Mbit/s.

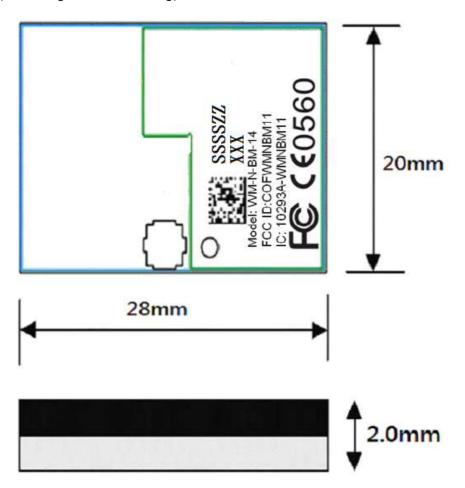
If need more detail information, please refer to STM32F205RG I/O or Interface manual.

9 DIMENSIONS, WEIGHT AND MOUNTING

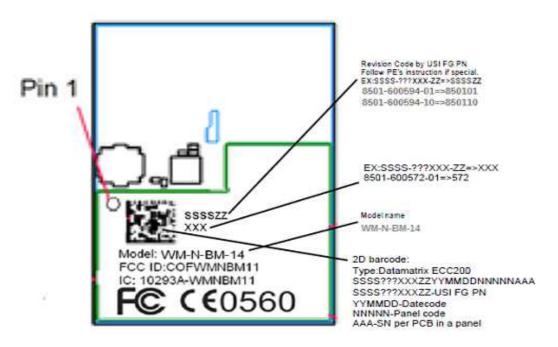
The following paragraphs provide the requirements for the size, weight and mounting of the WM-N-BM-14 module.

9.1 Dimensions

The size and thickness of the WM-N-BM-14 module is "28 mm (W) x 20 mm (L) x 2.0 mm (H) \pm 0.1 mm " (Including metal shielding)

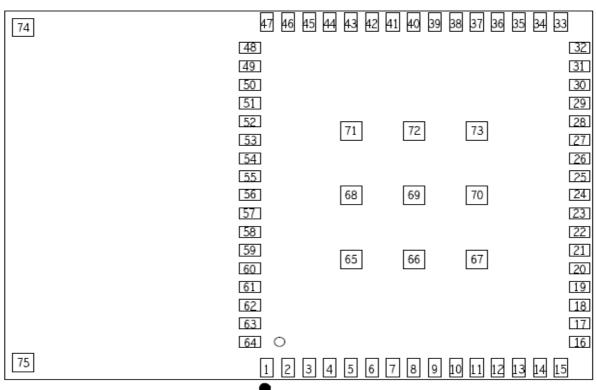


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9.2 Pin Out and Pin Description

PIN OUT



Top View

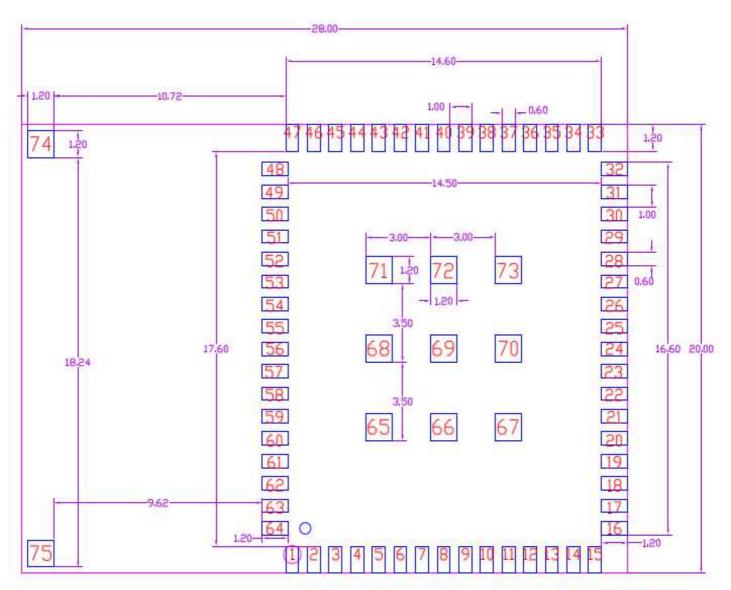
Pin Description

Pin-Number	Pin-Define	Туре	Description
1	GND		Ground
2	VBAT_WL	I	Battery supply input
3	VBAT_WL	l	Battery supply input
4	GND		Ground
5	VDDIO_3V3_WL	I	Digital I/O supply.
6	GND		Ground
7	WL_REG_ON		WiFi reset .
8	NC		
9	NC		
10	NC		
11	NC		
12	NC		
13	GND		Ground
14	NC		
15	GND		Ground
16			For normal operation, if JTAG is not used, this pin can be left unconnected (NC).
10	WL_JTAG_TDI	I/O	2. This pin is also muxed UART_RX, which can be enabled by software.
17	WL_JTAG_TCK	ı	For normal operation, if JTAG is not used, this pin can be left unconnected (NC).
18	WL_JTAG_TRST	1	For normal operation, if JTAG is not used, this pin can be left unconnected (NC).
19	WL_JTAG_TMS	I	For normal operation, if JTAG is not used, this pin can be left unconnected (NC).
20			For normal operation, if JTAG is not used, this pin can be left unconnected (NC).
	WL_JTAG_TDO	I/O	2. This pin is also muxed UART_TX, which can be enabled by software.

Pin-Number	Pin-Define	Туре	Description
21	MICRO_SPI1_MISO		SPI1_MISO
22	MICRO_SPI1_SCK	I/O	SPI1 CLOCK
23	MICRO_SPI1_MOSI	I/O	SPI1_MOSI
24	MICRO_SPI1_NSS	I/O	SPI1_NSS
25	GND		Ground
26	VDD_3V3	ı	Power supply for I/O and the internal regulator
27	VDD_3V3	I	Power supply for I/O and the internal regulator
28	GND		Ground
29	MICRO_UART2_RTS	I/O	MICRO_UART2_RTS
30	MICRO_UART2_CTS	I/O	MICRO_UART2_CTS
31	MICRO_UART2_RXD	I/O	MICRO_UART2_RXD
32	MICRO_UART2_TXD	I/O	MICRO_UART2_TXD
33	TESTMODE	I/O	GPIO pin
34	MICRO_RST_N	I	MICRO reset pin
35	MICRO_I2C1_SCL	I/O	the standard I2C communication protocol
36	MICRO_I2C1_SDA	I/O	the standard I2C communication protocol
37	GND		Ground
38	VBAT_MICRO	I	Power supply when VDD_3V3 is not present.
39	GND		Ground
40	MICRO_GPIO1	I/O	GPIO pin
41	MICRO_GPIO2	I/O	GPIO pin
42	MICRO_GPIO3	I/O	GPIO pin
43	MICRO_GPIO5	I/O	GPIO pin
44	MICRO_GPIO6	I/O	GPIO pin
45	MICRO_GPIO7 / I2S3_SD	I/O	GPIO pin / also can be used on I2S3_SD
46	MICRO_GPIO8 / I2S3_MCK	I/O	GPIO pin / also can be used on I2S3_MCK
47	MICRO_GPIO9	I/O	GPIO pin
48	MICRO_GPIO12	I/O	GPIO pin
49	MICRO_GPIO13	I/O	GPIO pin

Pin-Number	Pin-Define	Туре	Description
50	MICRO_GPIO14	I/O	GPIO pin
51	MICRO_JTAG_TRST	I	For normal operation, if JTAG is not used, this pin can be left unconnected (NC)
52	MICRO_JTAG_TDO / I2S3_SCK	I/O	 For normal operation, if JTAG is not used, this pin can be left unconnected (NC) also can be used on I2S3_SCK
53	MICRO_JTAG_TDI / I2S3_WS	I/O	 For normal operation, if JTAG is not used, this pin can be left unconnected (NC) also can be used on I2S3_WS
54	MICRO_JTAG_TMS	I	For normal operation, if JTAG is not used, this pin can be left unconnected (NC)
55	MICRO_JTAG_TCK	I	For normal operation, if JTAG is not used, this pin can be left unconnected (NC)
56	BTCX_STATUS		Multiplexed BT_Coex pin
57	BTCX_RF-ACTIVE		Multiplexed BT_Coex pin
58	BTCX_TXCONF		Multiplexed BT_Coex pin
59	GND		Ground
60	WL_SLEEP_CLK	I	Input pin for optional high- precision 32.768kHz Clock(Sleep Clock).
61	MICRO_UART1_RTS	I/O	Active-low request-to-send signal for UART interface
62	MICRO_UART1_CTS	I/O	Active-low clear-to-send signal for UART interface
63	MICRO_UART1_RXD	I/O	Serial data input for UART interface
64	MICRO_UART1_TXD	I/O	Serial data output for UART interface
65 ~ 73	GND		Ground

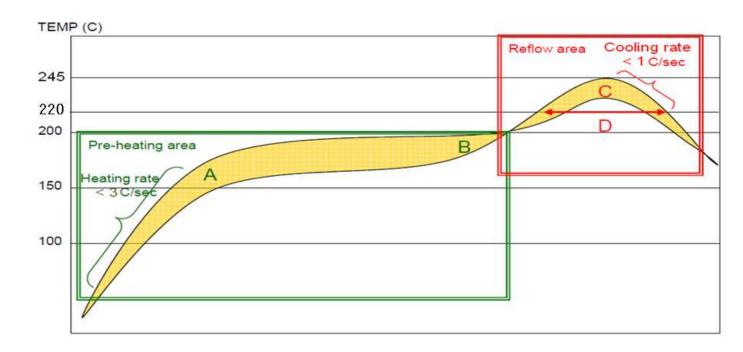
10 RECOMMEND FOOTPRINT



Unit:mm

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11 RECOMMEND REFLOW PROFILE



A-B. Temp.: 150~200°C; soak time:60~120sec.

C. Peak temp: 235~245°C

D. Time above 220 $^{\circ}\text{C}$: 40~90sec.

Suggestion: Optimal cooling rate is <1 $^{\circ}\text{C}$ /sec. from peak to 220 $^{\circ}\text{C}$.

12 PACKAGE AND STORAGE CONDITION

Universal Scientific Industrial Co., Ltd.

WM-N-BM-14 PACKAGING SPECIFICATION				PACKAGING SPECIFICATION			CONFIDENTIAL		
Project Name:	WM-N	-BM-14	Description: F		BCM43362 WICED Module				
适用之产品:	8501-600	594-01 / 10	4-01 / 10		Tape Carrier 之单元格尺寸:		Tape Carrier 之单元格尺寸:		97*PITCH 28(mm)
MSL information:	LEVEL:	3	3	温度(℃):	250	时间(hour):	168		

使用之包装材料:

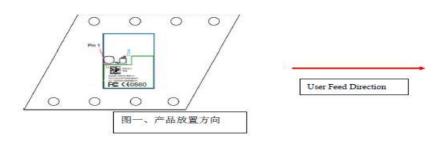
NO	品名	P/N	用量(以大箱计)
1	大 箱[360*140*360MM]	59-012485-11/21	1
2	Pizza 盒[340x336x40MM]	59-110015-02/12	2
3	产品标签(Reel/Bag/Box)	59-456702-01	6
4	CARRIER TAPE(載 带)[80M/REEL]	59-308419-01	
5	COVER TAPE (透 明 带)[300M/Reel]	59-733786-01	
6	REEL(载带滚动条)	59-303160-01/11	2
7	Protective band(保护带)[1 EA=1.09m]	59-733926-01	2
8	铝箔密封袋	59-357426-11	2
9	干燥剂 (66g)(CoCl2 Free)	59-393005-00	2
10	大箱标签	59-456703-01	1
11	湿度指示卡(CoCl2 Free)	59-201004-01	2
12	MSL LABEL(湿度敏感等级卷 标)	59-525934-01/11	2

包装方式: (1 卷共 2000PCS)

- 1. 将 Tape Carrier、Reel、Cover Tape 装上 tape reel 包装机, CARRIER TAPE 先预留 10-13 格空格后开始放产品,每 格放 1PCS。
- 2. 包装时产品的铁盖朝上放入 carrier,定位符号朝向 carrier 定位孔(图一),每卷 REEL 装 500PCS。 3. 在 500PCS 后请预留 10-13 格空格,产品卷装后用 COVER TAPE 再多绕一圈,最后用美纹胶带固定。 4. 在卷带后,再将保护带圈于 Reel 之外围,并以美纹胶黏贴固定。

- 5. 在 REEL、铝箔袋及纸盒各贴上一张 59-456702-01(空白标签 PN: 59-514157-01)产品标签(图二)。
 6. 每一铝箔密封袋放入一卷产品、一包干燥剂,及一片 6 格湿度指示卡,以真空包装机将袋口密封,如(图二)。
 7. 每一个铝箔密封袋上须加贴一张 MSL 标签在 ATTENTION 旁边,填写内容如(图四)所示。
 8. 将已真空包装 Reel 放入 PIZZA BOX 内,每大箱放 2 盒产品,如图五所示。
 9. 大箱贴一张 59-456703-01(空白标签 PN: 59-510010-00)的大箱标签,其填写格式:



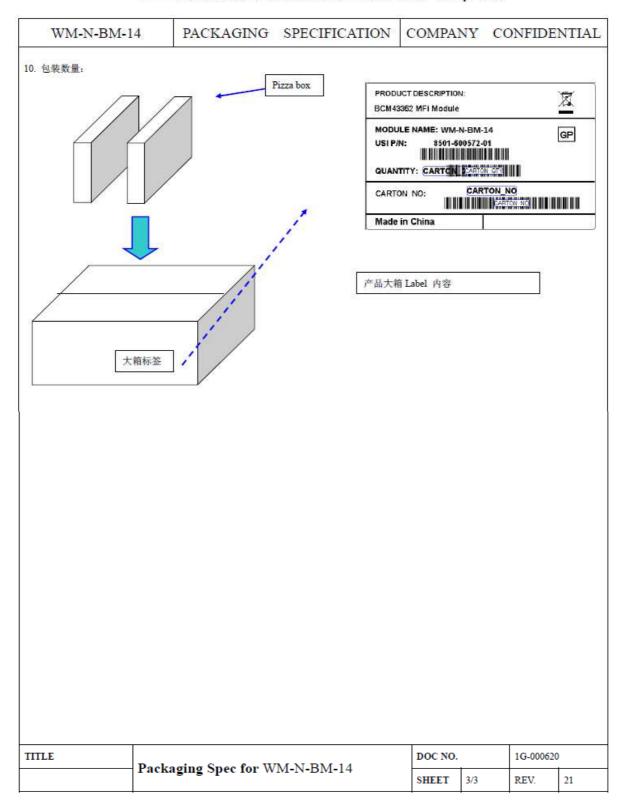


TITLE	Packaging Spec for WM-N-BM-14	DOC NO.	2533	1G-0006	520
	98500 (8650) 1750)	SHEET	1/3	REV.	21

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13 ESD LEVEL

Note:

1. Surface Resistivity:

Interior:10⁹~10¹¹Ω/SQUARE EXTERIOR:10⁸~10¹²Ω/SQUARE

2. Dimension:475*420mm

3. Tolerance:+5,0mm

4. Color:

Background: Gray

Text: Red

Length leader / trailer tape:

Leader tape: ≥550mm which includes ≥100mm of carrier tape with empty compartments and covered with tape; remaining part might be of cover tape only.

Trailer tape: ≥160mm with empty compartments and covered with tape.

NOTES:

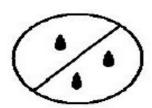
- 1. Material: Conductive Polystyrene (Recycle)
- 2. Color: Black
- 3. Surface resistance: Under 10⁶ Ohms/square.

Cumulative tolerance per 10 pictches(P₀) is ±0.2mm.

A₀ & B₀ are measured on the plane by 0.3mm above the bottom of the pocket.

- 4. K_0 is measured from the Inside bottom of the pocket to the top surface of the carrier.
- 5. <u>Pocket position relative to sprocket hold is measured as true position of pocket,</u> not sprocket hold.

14 MSL LEVEL / STORAGE CONDITION



CAUTION This bag contains MOISTURE-SENSITIVE DEVICES



- Calculated Shelf life in sealed bag: 12 months at < 40°C and < 90%Relative humidity (RH)
- Peak package body temperature 250 °C
 If Blank, see adjacent bar code label.
- After bag is opened, Devices that will be subjected to reflow solder or other high temperature process must
 Mounted within: 168 hrs. Of factory conditions ≤30 ℃/60% RH, OR

 If Blank, see adjacent bar code label
 - (b) Stored at < 10 CRH.
- 4. Devices require bake, before mounting, it:
 - (a) Humidity indicator Card is >10% when read at 23±5°C
 - (b) 3a or 3b not met.
- If baking is required, Devices may be baked for 24 hrs at 125±5°C
 Note: If device containers cannot be subjected to high temperature
 Or shorter bake times are desired. Reference IPC/JEDEC J-STD-033 for bake procedure
 Bag Seal Date: Note: Level and body temperature defined by IPC/JEDEC J-STD-020
 If Blank, see adjacent bar code label

Life cycle: 2 years

For Additional information, please contact the following:

Universal Scientific Industrial Co., Ltd. Headquarters

141, Lane 351, Taiping Road, Sec. 1, Tsao-Tuen, Taiwan,

Http://www.usi.com.tw

Tel: +886-49-2350876, 2325876

Fax: +886-49-3439561, 2337360,2351093

E-mail:usi@ms.usi.com.tw